

Dual operational amplifier

BA728 / BA728F / BA728N

The BA728, BA728F, and BA728N are ICs with two independently functioning operational amplifiers featuring internal phase compensation. These products offer a wide range of operating voltages, from 3 to 18V (± 1.5 to 9V) and are high-performance operational amplifiers which can be driven from a single power supply within the in-phase mode input range, including a negative power supply.

●Applications

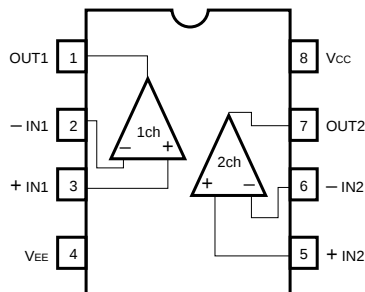
Ground sensing small-signal amplifiers
Control amplifiers requiring high phase margin, such as motor drivers
Amplifiers operated on low voltages
Capacitive loaded amplifiers

●Features

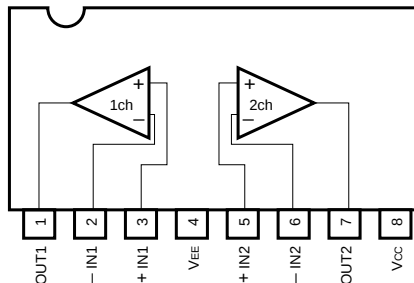
- 1) Can be driven from a single power supply.
- 2) Low power.
- 3) Pin layout is the same as that of the general-purpose 4558 operational amplifier.
- 4) When driven from a single power supply, the power supply voltage ranges from 3 to 18V.
- 5) When driven from a dual power supply, the power supply voltage ranges from ± 1.5 to $\pm 9V$.
- 6) Output is protected against short-circuits.
- 7) Output block is operated as a class AB to minimize crossover distortion.
- 8) Low input bias current of 10nA (typ.).
- 9) Each package contains two operational amplifiers.
- 10) Internal phase compensation provided.

●Block diagram

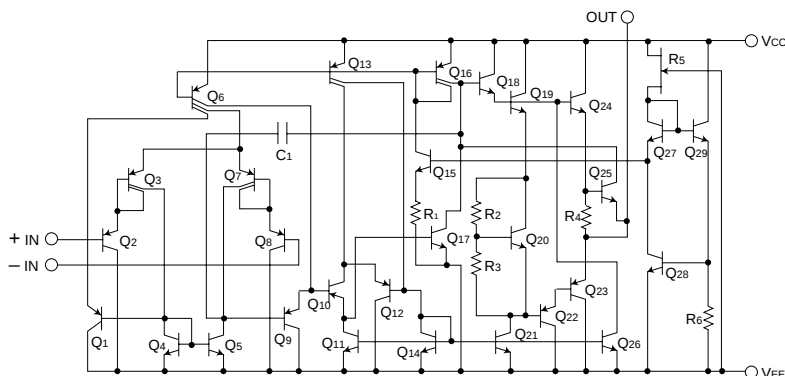
BA728 / BA728F



BA728N



● Internal circuit configuration



● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits			Unit
		BA728	BA728F	BA728N	
Power supply voltage	V _{CC}	18 (± 9)	18 (± 9)	18 (± 9)	V
Power dissipation	P _d	800*	550*	550*	mW
Differential input voltage	V _{ID}	V _{CC}	V _{CC}	V _{CC}	V
Common-mode input voltage	V _I	- 0.3 ~ + V _{CC}	- 0.3 ~ + V _{CC}	- 0.3 ~ + V _{CC}	V
Operating temperature	T _{opr}	- 20 ~ + 75	- 20 ~ + 75	- 20 ~ + 75	°C
Storage temperature	T _{stg}	- 55 ~ + 125	- 55 ~ + 125	- 55 ~ + 125	°C

* Refer to Pd characteristics diagram.

* The values for the BA728F are those when it is mounted on a glass epoxy PCB (50mm × 50mm × 1.6mm).

● Electrical characteristics (unless otherwise noted, Ta = 25°C, V_{CC} = + 6V, V_{EE} = - 6V)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Input offset voltage		V _{IO}	—	2	10	mV	
Input offset current		I _{IO}	—	1	50	nA	
Input bias current		I _B	—	10	250	nA	
High-amplitude voltage gain		A _v	86	100	—	dB	R _L ≥ 2kΩ
Common-mode input voltage		V _{ICM}	4 ~ - 6	4.5 ~ - 6	—	V	
Maximum output voltage		V _{OM}	± 3.0	± 4.5	—	V	R _L ≥ 2kΩ
Common mode rejection ratio		CMRR	70	90	—	dB	
Power supply voltage rejection ratio		PSRR	—	30	150	μV / V	
Slew rate		S. R.	—	0.7	—	V / μs	A _v = 1, R _L = 2kΩ
Maximum frequency		f _T	—	0.7	—	MHz	
Channel separation		CS	—	120	—	dB	
Maximum output current	source	I _{source}	—	20	—	mA	V _{IN} ⁺ = 1V, V _{IN} ⁻ = 0V
	sink	I _{sink}	—	10	—	mA	V _{IN} ⁻ = 1V, V _{IN} ⁺ = 0V

● Measurement circuits

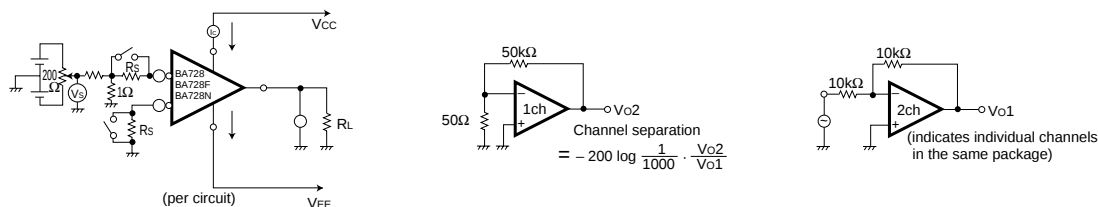


Fig. 1 Channel separation measurement circuit

● Electrical characteristic curves

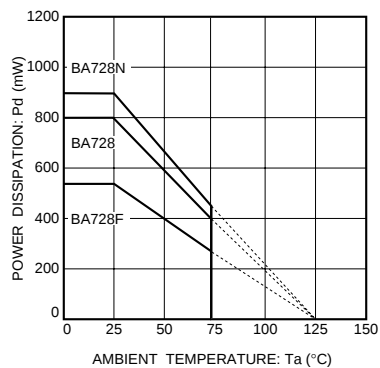


Fig.2 Power dissipation vs. ambient temperature

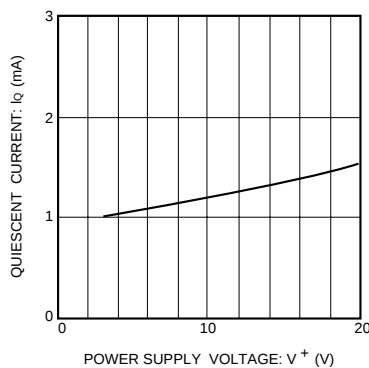


Fig.3 Quiescent current vs. power supply voltage

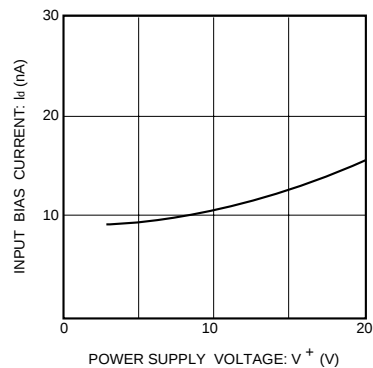


Fig.4 Input bias current vs. power supply voltage

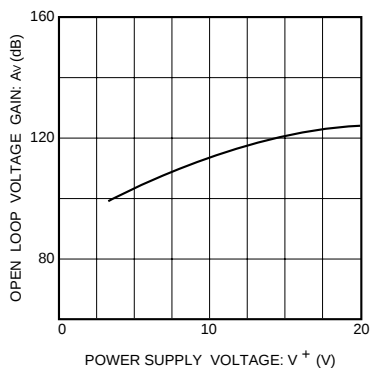


Fig.5 Open loop voltage gain vs. power supply voltage

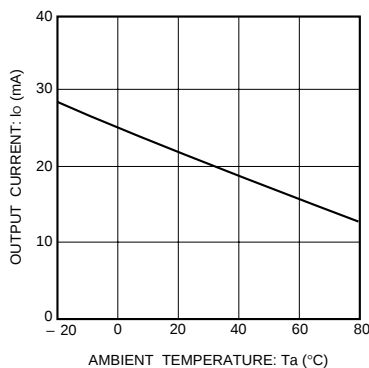


Fig.6 Current control characteristics

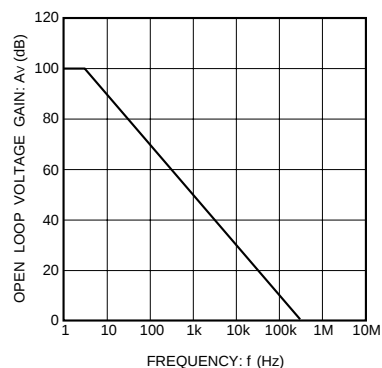


Fig.7 Open loop voltage gain vs. frequency

●Electrical characteristic curve

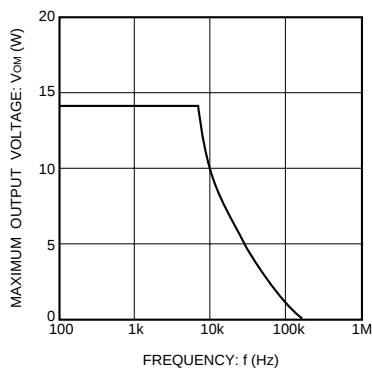


Fig.8 Maximum output voltage vs. frequency

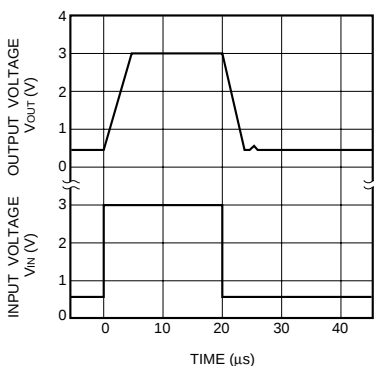


Fig.9 Output response characteristics

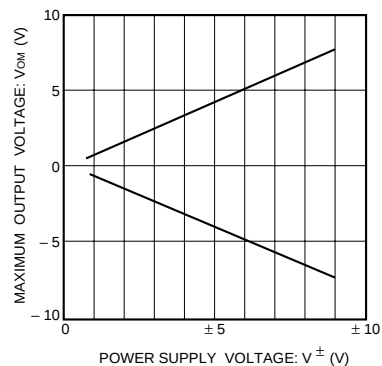


Fig.10 Maximum output voltage vs. power supply voltage

●Operation notes

(1)Unused circuit connections

If there are any circuits which are not being used, we recommend making connections as shown in Figure 11, with the non-inverted input pin connected to the potential within the in-phase input voltage range (V_{ICM}).

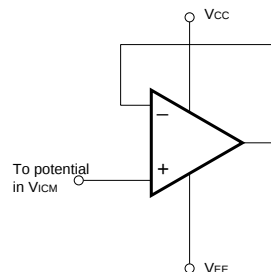


Fig.11 Unused circuit connections

●External dimensions (Units: mm)

